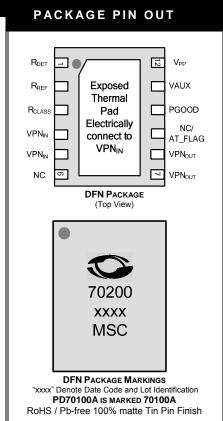


IEEE 802.3af/at PD Front End IC

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Notes: Exceeding these ratings could cause damage to the device. All voltages are with respect to VPN_{IN}. Currents are positive into, negative out of specified terminal. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" are not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.



	PACKAGE ORDER INFO	THERMAL DATA	
T (0C)	12 Pins DFN 4x3	40 ° C/W THERMAL RESISTANCE-JUNCTION TO AMBIENT	
T _A (°C)	RoHS Compliant / Pb-free	4 ° C/W THERMAL RESISTANCE-JUNCTION TO CASE	
-40 to 85	PD70100AILD (IEEE802.3af)	Junction Temperature Calculation: $T_J = T_A + (P_D \times \theta_{JA})$.	
10 10 00	PD70200ILD (IEEE802.3at)	The θ_{JA} numbers are guidelines for the thermal performance of the device/pc-board system. All of the above assume no	
Note: Available in Tape & Reel. Append the letters "TR" to the part number. (i.e. PD70200ILD-TR)		ambient airflow.	

ELECTRICAL CHARACTERISTICS

Unless otherwise specified, the following specifications apply over the operating ambient temperature -40°C \leq T_{AMB} \leq 85°C. Production tests are done at 25°C T_A.

Parameter	Symbol	Test Conditions / Comment	Min	Тур	Max	Units
Power Supply						
Input Voltage	V_{PP}	Supports Full IEEE802.3 af/at functionality	0	55	57	V
Power Supply Current at Operating Mode		V _{PP} = 55V		1	3	mA

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ELECTRICAL CHARACTERISTICS

Unless otherwise specified, the following specifications apply over the operating ambient temperature -40°C \leq T_{AMB} \leq 85°C. Production tests are done at 25°C T_A.

Parameter	Symbol	Test Conditions / Comment	Min	Тур	Max	Units
DETECTION MODE	1					
Detection is connected. At this voltage range R _{DET} must be on.	DET _{RANGE}	Measured between V _{PP} and VPN _{IN}	1.3		10.1	V
Detection Switch ON Resistance PD-detection	R _{DET} -on	2.5V ≤ $(\Delta V_{PP}$ to $VPN_{IN})$ ≤ 10.1V Measured between R_{DET} and VPN_{IN}			50	Ω
Detection is Disconnected	R _{DET} -off	Measured between V _{PP} and VPN _{IN}	10.1		12.8	V
Detection Switch OFF Resistance	R _{DET} -off	12.8V ≤ (ΔV_{PP} to VPN _{IN}) ≤ 57.0V Measured between R _{DET} and VPN _{IN}	2.0			ΜΩ
Input Offact Current	I _{OFFSET}	1.1V to 10.1V -40°C ≤ T _J ≤ 85°C			16	μA
Input Offset Current	I _{OFFSET}	1.1V to 10.1V -40°C ≤ T _J ≤ 55°C			10	μA
CLASSIFICATION MODE						
Classification Current Source, Turn ON Threshold Range Measured at V _{PP}	V _{TH} -low-on	Turn on for any I _{CLASS} while V _{PP} increases	11.4		13.7	V
Classification Current Source, Turn OFF Threshold Range Measured at V _{PP}	V _{TH} -high-off	Turn off while V _{PP} increases	20.9		23.9	٧
Current Limit Threshold	I _{CLASS} -LIM		50.0	68	80.0	mA
Input Current I _{PP} When Classification Function is Disabled	I _{CLASS} -DIS	Class 0 R _{CLASS} =Disconnect			4.0	mA
	I _{CLASS} -EN	Class 1 R _{CLASS} = 133Ω±1%	9.0	10.5	12.0	mA
Input Current I _{PP} When Classification		Class 2 R _{CLASS} = 69.8 Ω±1%	17.0	18.5	20.0	mA
Function is Enabled	ICLASS*LIV	Class 3 R _{CLASS} = 45.3 Ω±1%	26.0	28.0	30.0	mA
		Class 4 R _{CLASS} = 30.9 Ω±1%	36.0	40.0	44.0	mA
MARK						
Mark, Working Voltage Range	V_{MARK}	When voltage decreases Measured between V _{PP} to VPN _{IN}	4.9		10.1	V
Mark Current	I _{MARK}	Chip current	0.25		4	mA
ISOLATION SWITCH						
Isolation Switch MOSFET Switches from Off to I _{LIM-LOW}	V _{SW-START}		36		42	V
Isolation Switch MOSFET Switched Off	V_{SW-OFF}		30.5		34.5	V
Startup Current Limit, I _{LIM}	I _{LIM-LOW}		105	240	325	mA
VPN _{IN} to VPN _{OUT} Threshold Voltage for I _{LIM - LOW} to I _{LIM-HIGH} Switchover	V_{DIFF}	When VPN _{IN} to VPN _{OUT} ≤ V _{DIFF} , Isolating switch			0.7	V

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ELECTRICAL CHARACTERISTICS

Unless otherwise specified, the following specifications apply over the operating ambient temperature -40°C \leq T_{AMB} \leq 85°C. Production tests are done at 25°C T_A.

Parameter	Symbol	Test Conditions / Comment	Min	Тур	Max	Units
		switches over from I _{LIM-LOW} to I _{LIM-HIGH} .				
Over Current Protection Current Limit	OCP		1500	1800	2000	mA
Continuous Operation Load Current	I _{LOAD}	Isolating switch at I _{LIM-HIGH} PD70100A PD70200		350 600	450 1123	mA mA
Continuous Operation Total RDS _{ON}	SW-RDS _{ON}	Total resistance between VPN _{IN} and VPN _{OUT} Isolating switch at I _{LIM-HIGH}			0.6	Ω
DC/DC CAPACITOR DISCHARGER						
DC/DC Input Capacitance		For reference only Guaranteed by design (not tested on production)		220		μF
Discharge Current.		7.0V ≤ VPP to VPN _{OUT} ≤ 30V	22.8	32	50	mA
Full Discharge Time for Full Discharge of Input Capacitance	T _{DSC}	V _{PP} < UVLO threshold Guaranteed by design (not tested in production)			500	ms
AT_FLAG						
Output Low Voltage		$I_{OL} = 0.75$ mA I_{OL} MAX = 5mA			0.4 2.5	V
Leakage Current		V _{ATFLAG} = 57V			1.7	μA
PGOOD		-AITENO VII				
Output Low Voltage		$I_{OL} = 0.75$ mA I_{OL} MAX = 5mA			0.4	V
Leakage Current		$V_{PGOOD} = 57V$			1.7	μA
THERMAL SHUTDOWN						
Thermal Shutdown Temperature			180	200	220	°C
VAUX (Reference to VPN _{OUT)}						
VAUX Output Voltage On	VAUX-on	Isolating switch at I _{LIM-HIGH} and PGOOD = Low	9.5	10.5	11.8	V
Output Current Peak	I _{VAUXP}	Capacitor = 30uF When T _{LOAD} ≤ 5mS Isolating switch at I _{LIM-HIGH} and PGOOD = Low	0		10	mA
Output Continuous Current	I _{VAUXC}	When T _{LOAD} ≤10mS Isolating switch at I _{LIM-HIGH} and PGOOD = Low	0		2	mA
VAUX Output Current Limit	I _{VAUX}	Isolating switch at I _{LIM-HIGH} and PGOOD = Low	10		32	mA

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PRODUCT DATASHEET

PD70100A Functional Block Diagram

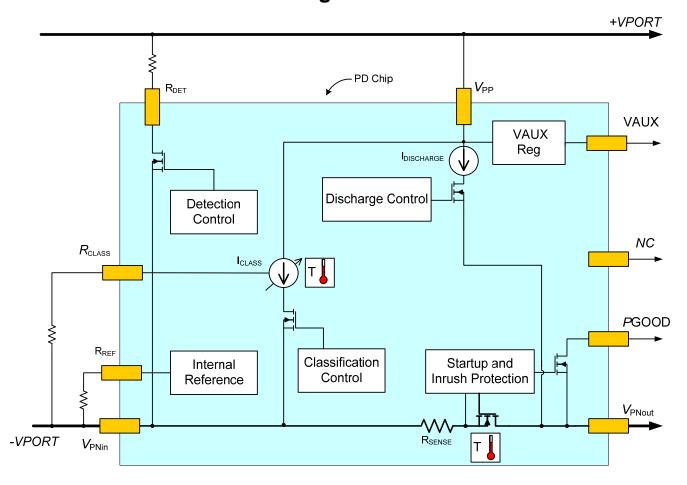


Figure 1: PD70100A Functional Block Diagram



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PD70200 Functional Block Diagram

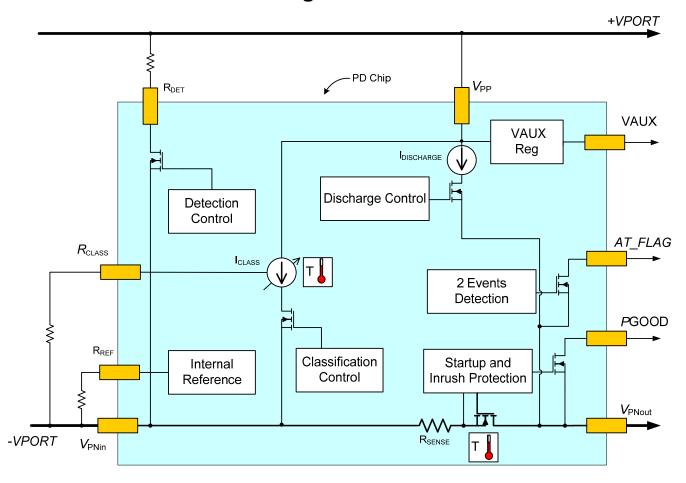


Figure 2: PD70200 Functional Block Diagram



IEEE 802.3af/at PD Front End IC

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	FUNCTIONAL PIN DESCRIPTION						
Pin	PD70100A Pin Name	PD70200 Pin Name	Туре	Description			
1	R _{DET}	R _{DET}		Valid Detection resistor. Connect external 24.9K Ω detection resistor between RDET and VPP			
2	R _{REF}	R _{REF}		Bias current resistor			
3	R _{CLASS}	R _{CLASS}		Power classification setting. Connect external class resistor between RCLASS and VPN _{IN}			
4	VPN _{IN}	VPN _{IN}	D	VPort Negative input. Connected to the isolating SW input. N-channel MOSFET source. The exposed thermal PAD should be			
5	VEININ	VEININ	Power	connect to these pins.			
6	N.C	N.C					
7	VDN	VON		Vport Negative output. Connected to the isolating SW output. N-channel MOSFET Drain. Primary side Ground.			
8	VPN _{OUT}	VPN _{OUT}	Power/Gnd	A decent ground plane should be deployed around this pin whenever is possible			
9	N.C	AT_FLAG	Open drain	The two-event detector should discern between AF and AT classification waveforms and outputs the AT_FLAG (PD70200 only)			
10	PGOOD	PGOOD	Open drain	After startup a PGOOD flag is generated in order to optionally inform the application DC/DC converter that the power rails are ready.			
11	VAUX	VAUX	Power	Auxiliary output voltage to VPN _{OUT} .			
			. 5.1.6.	Can be used for DC-DC startup for bootstrap initiation.			
12	VPP	VPP	Power	High voltage positive input, reference to VPN _{IN} and high voltage positive input, reference to VPN _{OUT} during capacitor discharge			
EP	EPAD	EPAD		Connect to VPN _{IN} . EPAD should be connected to a large copper area for improved thermal management.			



PRODUCT DATASHEET

THEORY OF OPERATION

DETAIL DESCRIPTION

PD70100A/PD70200 IC provides IEEE 802.3af/at compliant PD Front-End functions including Detection, Physical Layer Classification, Two-Events Classification (PD70200 only), Auxiliary Voltage Output, Power Good, Soft-Start Current Limiting, Over-Current Protection, and Bulk Capacitor Discharge.

DETECTION

IEEE 802.3af/at compliant detection is provided by means of a 24.9KΩ resistor connected between V_{PP} and R_{DET} pin. R_{DET} pin is connected to VPN_{IN} via an open drain MOSFET with a maximum specified RDS_{\text{ON}} of 50Ω. Internal logic monitors V_{PP} to VPN_{IN} and connects the R_{DET} pin to VPN_{IN} when the rising V_{PP} to VPN_{IN} voltage is between 2.5V and 10.1V. When rising V_{PP} to VPN_{IN} voltage exceeds 10.1V, the MOSFET is switched off. Once above 10.1V, falling V_{PP} to VPN_{IN} voltage between 2.45V and 4.85V will reconnect R_{DET} pin to VPN_{IN} .

PHYSICAL LAYER CLASSIFICATION

Physical Layer (hardware) Classification per IEEE 802.3af/at is generated via a regulated reference voltage of 1.2V, switched onto the $R_{\rm CLASS}$ pin. Internal logic monitors the $V_{\rm PP}$ to $VPN_{\rm IN}$ voltage and connects the 1.2V reference to $R_{\rm CLASS}$ pin at a rising $V_{\rm PP}$ to $VPN_{\rm IN}$ voltage threshold between 11.1V and 13.5V. Once $V_{\rm PP}$ to $VPN_{\rm IN}$ has exceeded the rising threshold, there is a 1V minimum hysteresis between the $V_{\rm PP}$ rising (turn-on) threshold and the $V_{\rm PP}$ falling (turn-off) threshold.

The 1.2V reference stays connected to the R_{CLASS} pin until the V_{PP} to VPN_{IN} rising voltage exceeds the upper turn-off threshold of 20.9V to 23.9V. The 1.2V reference voltage is disconnected from the R_{CLASS} pin at V_{PP} to VPN_{IN} voltages above the upper threshold.

Classification current signature is provided via a resistor connected between R_{CLASS} pin and $\text{VPN}_{\text{IN}}.$ The classification current is therefore the current drawn by the PD70100A/PD70200 IC during the classification phase, and is simply the 1.2V reference voltage divided by the R_{CLASS} resistor value. The maximum current available at the R_{CLASS} pin is current limited to 55mA (typical).

TWO-EVENTS DETECTION AND AT FLAG

The PD70200 IC provides IEEE 802.3at Type 2 compliant detection of the "Two Events Classification Signature", and generation of the AT flag. This feature is available on the PD70200 IC only.

Simply put, the "Two Events Classification Signature" is a means by which an IEEE 802.3at Type 2 Power Source can inform a compliant Power Device (PD) that it is AT Type 2 compliant, and as such is capable of providing AT Type 2 power levels.

The Power Source communicates with a Type 2 compliant signature by toggling the V_{PP} to VPN_{IN} voltage twice (2 "events") during the Physical Layer Classification phase. The V_{PP} to VPN_{IN} voltage is toggled from the Physical Layer Classification's voltage level (13.5V to 20.9V) down to a voltage "Mark" level. Voltage "Mark" level is specified as a V_{PP} to VPN_{IN} voltage of 4.9V to 10.1V.

PD70200 IC recognizes a V_{PP} to VPN_{IN} falling edge from Classification level to Mark level as being one event of the Two-Events Signature. If two such falling edges are detected, PD70200 will assert AT flag by means of an open drain MOSFET connected between AT_FLAG pin and VPN_{OUT} .

AT_FLAG pin is active low; a low impedance state between AT_FLAG and VPN_{OUT} indicates a valid Two-Events Classification Signature was received, and the Power Source is AT Type 2 compliant.

AT_FLAG MOSFET is capable of 5mA of current and can be pulled up to V_{PP} .

SOFT START AND INRUSH CURRENT PROTECTION

PD70100A/PD70200 IC contains an internal isolation switch, that provides ground isolation between Power Source and PD application during Detection and Classification phases. The isolation switch is a N-channel MOSFET, wired in a common source configuration where the MOSFET's Source is connected to Power Source ground at VPN $_{\rm IN}$, and the MOSFET's Drain is connected to application's primary ground at VPN $_{\rm OUT}$.



PRODUCT DATASHEET

THEORY OF OPERATION

Internal logic monitors V_{PP} to VPN_{IN} voltage and keeps the MOSFET in a high impedance state until V_{PP} to VPN_{IN} voltage reaches turn-on threshold of 36V to 42V. Once V_{PP} to VPN_{IN} voltage exceeds this threshold, the MOSFET is switched into one of two modes.

The mode into which the MOSFET is switched is determined by the voltage developed across the MOSFET, or put another way, the VPN_{OUT} to VPN_{IN} differential voltage. Two modes are defined below:

Isolation Switch Modes					
VPN _{OUT} to VPN _{IN}	Mode	Description			
> 0.7V	Soft Start Mode	Limits VPN _{OUT} current to 240mA (typical)			
≤ 0.7V	Normal Operating Mode	Limits VPN _{OUT} current to 1.8A (typical)			

By controlling the MOSFET current based on VPN_{OUT} to VPN_{IN} voltage, inrush currents generated by fully discharged bulk capacitors can be limited. This method limits current to a maximum of 350mA, compliant with IEEE 802.3af/at specification.

Soft Start current limiting is required to reduce occurrences of voltage sag at the PD input during device power-up. A comparison is shown in Figure 3.

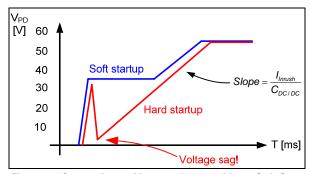


Figure 3. Comparison of input voltages without Soft Start (Hard startup), and with Soft Start (Soft startup).

Once bulk capacitance has charged up to a point where VPN_{OUT} to VPN_{IN} differential voltage is less than 0.7V, the isolation MOSFET is switched into normal operating mode with MOSFET current limit set at 1.8A (typical), to provide over-current protection.

PD70100A and PD70200 ICs are different in their respective isolation MOSFET's continuous current handling capability:

PD70100A: 450mA (max.) PD70200: 1123mA (max.)

An adequate heat sink for the PD70100A/PD70200 IC's exposed pad must be provided to achieve these current levels without damaging the IC. A large, heavy copper fill area and/or a heavy ground plane with Thermal Vias is recommended. Electrically the exposed pad ground plane should be connected to VPN_{IN} .

Internal logic monitoring V_{PP} to VPN_{IN} will place the isolation switch MOSFET in a high impedance state if voltage between V_{PP} and VPN_{IN} drops below 31V to 34V.

OVER-CURRENT PROTECTION

Over-current protection is provided on the PD70100A/PD70200 IC using the Isolation MOSFET Switch, which limits the VPN $_{\rm OUT}$ current to 1.8A during normal operation. See previous description of Soft Start.

POWER GOOD

During Soft-Start mode, the PD70100A/PD70200 IC monitors VPN_{OUT} to VPN_{IN} differential voltage. When this voltage is less than 0.7V (max.), the IC enters normal operation mode and the isolation switch current limit is increased to 1.8A (typical). At this same 0.7V (max.) threshold the Power Good signal is asserted by means of an open drain MOSFET between PGOOD and VPN_{OUT} .

PGOOD pin is active low; a low impedance state between PGOOD and VPN_{OUT} indicates the Soft-start mode has finished and the isolation switch has transitioned into normal operating mode.

PGOOD MOSFET can handle current of 5mA and can be pulled up to $V_{\mbox{\footnotesize{PP}}}.$



IEEE 802.3af/at PD Front End IC

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THEORY OF OPERATION

AUXILIARY VOLTAGE OUTPUT

PD70100A/PD70200 IC provides a 10.5V (typical) regulated output to be used as a start-up supply for DC/DC controllers whose V_{CC} is provided via a bootstrap winding. This regulated supply is available at VAUX pin, and is referenced to VPN_{OUT} pin. VAUX supply is designed for low-duty operation, and should not be designed as a primary housekeeping supply. The current capability is continuous 2mA, with 10mA peak (≤10ms). VAUX output is current-limited at 10mA (min.).

For stability, the VAUX regulator requires a minimum of 4.7µF ceramic capacitor connected directly between VAUX and VPN_{OUT} pins.

THERMAL PROTECTION

Both PD70100A and PD70200 IC include temperature sensors which individually monitor both the isolation MOSFET and the Classification Current Source for over temperature conditions. In case of an over temperature condition, the sensor will activate protection circuitry which will disconnect its respective monitored function.

BULK CAPACITOR DISCHARGE

The bulk capacitor discharge circuitry eliminates the need to place a diode in series with the V_{PP} line to prevent an application's bulk capacitance from discharging through the detection resistor and the isolation switch MOSFET's body diode. Discharge current through the detection resistor can cause failure of the detection signature in cases where a PD is connected and the bulk capacitance is not fully discharged.

During normal operation, PD70100A/PD70200 continuously monitors voltage at V_{PP} to VPN_{IN} . Should V_{PP} to VPN_{IN} voltage fall below isolation switch turn-off threshold (31V to 34V), isolation switch MOSFET is immediately placed in a high-impedance state. At this point the internal logic monitors the voltage at V_{PP} to VPN_{OUT} . If V_{PP} to VPN_{OUT} voltage is between 1.5V to 32V, a 23mA (min.) constant current source is connected across the $V_{\mbox{\scriptsize PP}}$ and VPN_{OUT} pins. This constant current source provides bulk capacitor discharge.

A 220µF bulk capacitance can be discharged from 32V to 1.5V in a maximal period of 292ms.

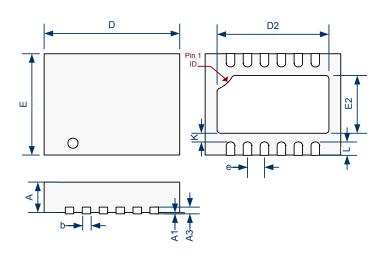


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LD

12 Pin Plastic DFN 4x3 mm



	MILLIM	1ETERS	INCHES		
Dim	MIN	MAX	MIN	MAX	
Α	0.80	1.00	0.031	0.039	
A1	0.00	0.05	0.000	0.002	
A3	0.20	REF	0.008 REF		
D	4.00	BSC	0.157 BSC		
E	3.00	BSC	0.118 BSC		
D2	3.00	3.70	0.118	0.146	
E2	1.40	1.80	0.055	0.071	
е	0.50 BSC		0.0197 BSC		
K	0.20 MIN		0.008 MIN		
L	0.30	0.50	0.012	0.020	
b	0.18	0.30	0.007	0.012	

Note:

1. Dimensions do not include mold flash or protrusions; these shall not exceed 0.155mm(.006") on any side. Lead dimension shall not include solder coverage.



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Revision Level / Para. Affected	Description	
Date		
0.1 / April 2010	Preliminary Release	
0.3 / June 2010	Add Classification Pulse Diagrams	
0.3 27 Jul 10	Changing catalog numbers metrology	
0.3 12 Nov 10	Extensive changes to document format and Theory of Operation; corrected package drawing; added Product Highlight and Typical Characteristics	
0.4 Dec 23 2010	Package update	
0.5 Jan 05 2011	Package update	
0.6 Jul 13 2011	Specification Update	
1.0 March 2012	Updated Document Address Footer & Characteristics	

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